

## BC327/328

### Switching and Amplifier Applications

- Suitable for AF-Driver stages and low power output stages
- Complement to BC337/BC338



### PNP Epitaxial Silicon Transistor

#### Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

| Symbol    | Parameter                   | Value     | Units            |
|-----------|-----------------------------|-----------|------------------|
| $V_{CES}$ | Collector-Emitter Voltage   |           |                  |
|           | : BC327                     | -50       | V                |
|           | : BC328                     | -30       | V                |
| $V_{CEO}$ | Collector-Emitter Voltage   |           |                  |
|           | : BC327                     | -45       | V                |
|           | : BC328                     | -25       | V                |
| $V_{EBO}$ | Emitter-Base Voltage        | -5        | V                |
| $I_C$     | Collector Current (DC)      | -800      | mA               |
| $P_C$     | Collector Power Dissipation | 625       | mW               |
| $T_J$     | Junction Temperature        | 150       | $^\circ\text{C}$ |
| $T_{STG}$ | Storage Temperature         | -55 ~ 150 | $^\circ\text{C}$ |

#### Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

| Symbol               | Parameter                            | Test Condition   | Min. | Typ. | Max. | Units |
|----------------------|--------------------------------------|--|------|------|------|-------|
| $BV_{CEO}$           | Collector-Emitter Breakdown Voltage  | $I_C = -10\text{mA}, I_B = 0$  | -45  |      |      | V     |
|                      |                                      |  | -25  |      |      | V     |
| $BV_{CES}$           | Collector-Emitter Breakdown Voltage  | $I_C = -0.1\text{mA}, V_{BE} = 0$  | -50  |      |      | V     |
|                      |                                      |  | -30  |      |      | V     |
| $BV_{EBO}$           | Emitter-Base Breakdown Voltage       | $I_E = -10\mu\text{A}, I_C = 0$  | -5   |      |      | V     |
| $I_{CES}$            | Collector Cut-off Current            | $V_{CE} = -45\text{V}, V_{BE} = 0$<br>$V_{CE} = -25\text{V}, V_{BE} = 0$ |      | -2   | -100 | nA    |
|                      |                                      |  |      | -2   | -100 | nA    |
| $h_{FE1}$            | DC Current Gain                      | $V_{CE} = -1\text{V}, I_C = -100\text{mA}$                               | 100  |      | 630  |       |
| $h_{FE2}$            |                                      | $V_{CE} = -1\text{V}, I_C = -300\text{mA}$                               | 40   |      |      |       |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = -500\text{mA}, I_B = -50\text{mA}$                                |      |      | -0.7 | V     |
| $V_{BE}(\text{on})$  | Base-Emitter On Voltage              | $V_{CE} = -1\text{V}, I_C = -300\text{mA}$                               |      |      | -1.2 | V     |
| $f_T$                | Current Gain Bandwidth Product       | $V_{CE} = -5\text{V}, I_C = -10\text{mA}, f = 20\text{MHz}$              |      | 100  |      | MHz   |
| $C_{ob}$             | Output Capacitance                   | $V_{CB} = -10\text{V}, I_E = 0, f = 1\text{MHz}$                         |      | 12   |      | pF    |

### $h_{FE}$ Classification

| Classification | 16        | 25        | 40        |
|----------------|-----------|-----------|-----------|
| $h_{FE1}$      | 100 ~ 250 | 160 ~ 400 | 250 ~ 630 |
| $h_{FE2}$      | 60-       | 100-      | 170-      |

# Typical Characteristics



Figure 1. Static Characteristic

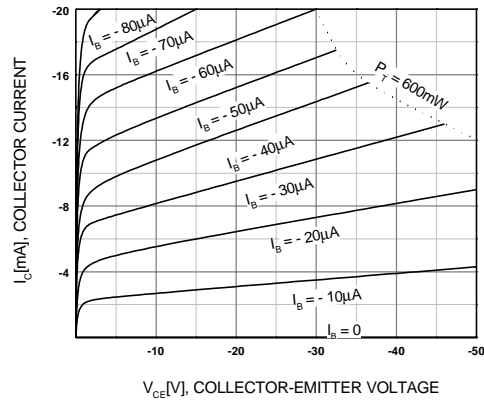


Figure 2. Static Characteristic



Figure 3. DC current Gain



Figure 4. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage



Figure 5. Base-Emitter On Voltage

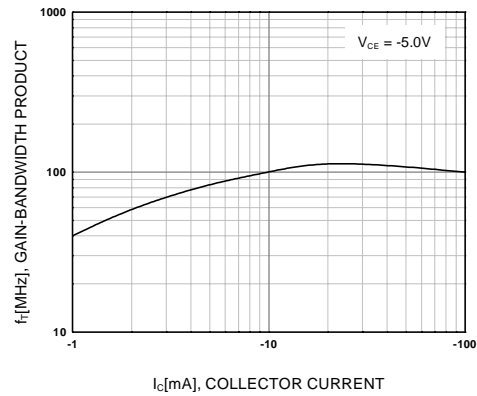


Figure 6. Gain Bandwidth Product

# Package Dimensions

BC327/328

## TO-92



Dimensions in Millimeters

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